

Commercial Availability & Testing (COTS MMICs)



- **GaAs pHEMT and HJFET Low Noise Transistors**
- **Noise Figure between 0,3 and 0,6 dB**
- **Total Gain approximately 12/13 dB (1 stage)**
- **Noise and S-parameters Provided by manufacturer**

| | Company | NF (dB) | GAIN (dB) | @Freq. (GHz) |
|-----------------------|------------|---------|-----------|--------------|
| MGF4953 | Mitsubishi | 0,40 | 13,5 | 12 |
| MGF4941 | Mitsubishi | 0,35 | 13,5 | 12 |
| MGF4419 | Mitsubishi | 0,50 | 12 | 12 |
| ATF-36077 | Agilent | 0,5 | 12 | 12 |
| MGF4931 | Mitsubishi | 0,60 | 11,5 | 12 |
| NE3511S0 ₂ | NEC | 0,30 | 13,5 | 12 |
| FHX13X | Fujitsu | 0,45 | 13 | 12 |

ATF-36077 Typical Noise Parameters,

Common Source, $Z_0 = 50 \Omega$, $V_{DS} = 1.5 \text{ V}$, $I_D = 10 \text{ mA}$

| Freq. GHz | $F_{min}^{(1)}$ dB | Γ_{opt} | | R_p/Z_0 - |
|--------------|-----------------------|----------------|------|----------------|
| | | Mag. | Ang. | |
| 1 | 0.30 | 0.95 | 12 | 0.40 |
| 2 | 0.30 | 0.90 | 25 | 0.20 |
| 4 | 0.30 | 0.81 | 51 | 0.17 |
| 6 | 0.30 | 0.73 | 76 | 0.13 |
| 8 | 0.37 | 0.66 | 102 | 0.09 |
| 10 | 0.44 | 0.60 | 129 | 0.05 |
| 12 | 0.50 | 0.54 | 156 | 0.03 |
| 14 | 0.56 | 0.48 | -174 | 0.02 |
| 16 | 0.61 | 0.43 | -139 | 0.05 |
| 18 | 0.65 | 0.39 | -100 | 0.09 |

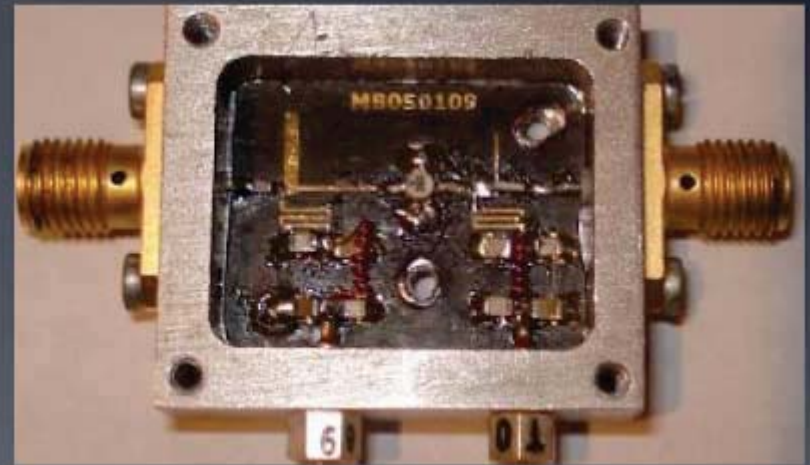
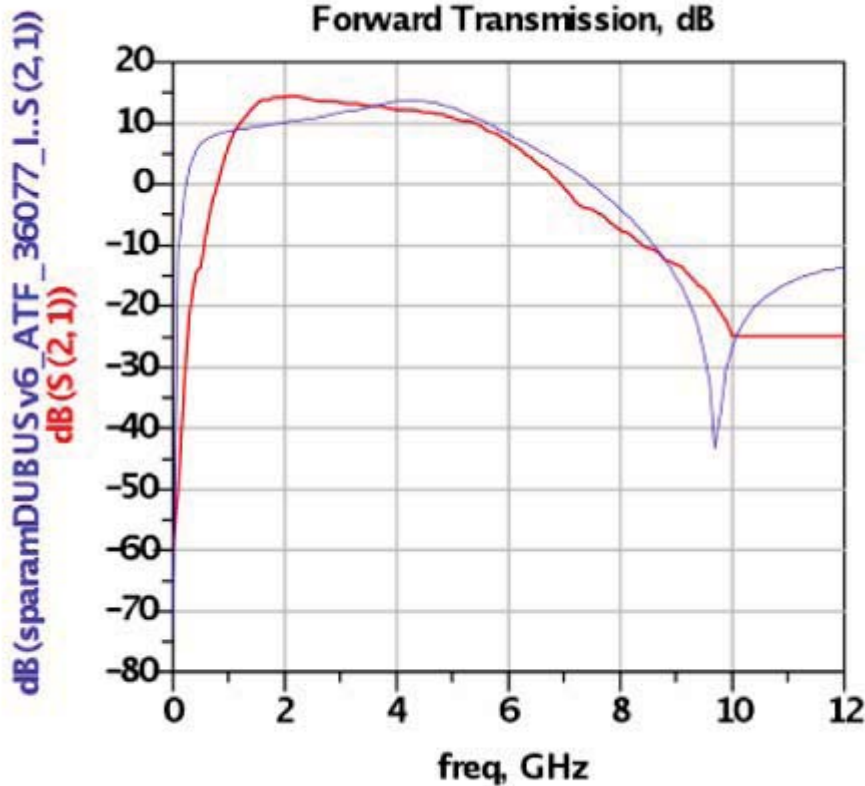
First pass: SIMULATIONS

- **S and Noise Parameters provided by the manufacturer**
- **Challenge is to create good matching networks, that will provide the lowest NF;**
- **Obtain low NF for a wide frequency band.**

| Device | NF(dB @ 5GHz) | GAIN(dB @ 5GHz) |
|--------------------------|---------------|-----------------|
| MGF4941 from Mitsubishi | 0,25 | 13,8 |
| MGFC4419 from Mitsubishi | 0,28 | 12,3 |
| MGF4931 from Mitsubishi | 0,48 | 11 |
| ATF-36077 from Agilent | 0.38 | 13 |
| NE3511S02 from NEC | 0,25 | 13 |
| FHX13X from Fujitsu | ----- | 14 |

(Second pass: Production Example: Avago ATF-36077)

Using the Noise Parameters provided, a LNA with $NF=0,38$ dB and 13,4dB of gain was implemented (room T)



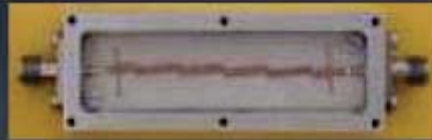
Elements for cascadable 100dB+ Gain Chain (Applied to GEM-P project)



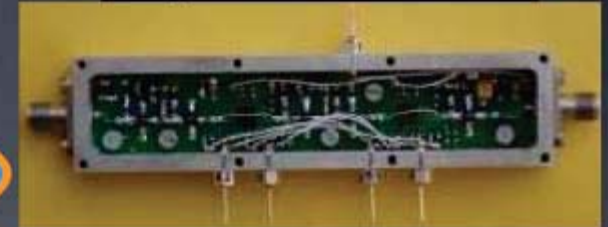
B=200MHz; 31dB; Butterworth
MMIC (best response flatness)



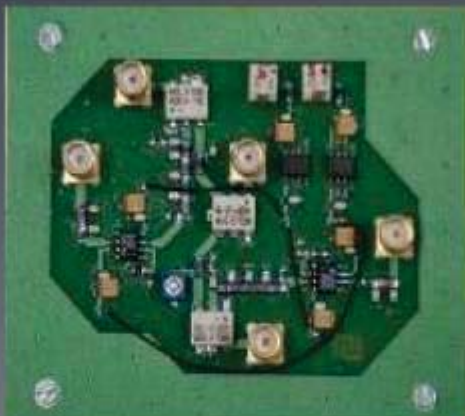
4.9GHz; B=600MHz
Coupled Line filter
RO4003



Flat gain; 71dB;
Digital attenuation



IF Chain+RF Filter



120dB isolation between ports



Frequency 600MHz; VCO; MMIC Amp.;
PLL synthesizer; 7dBm

Sunpower Cryocooler evaluation

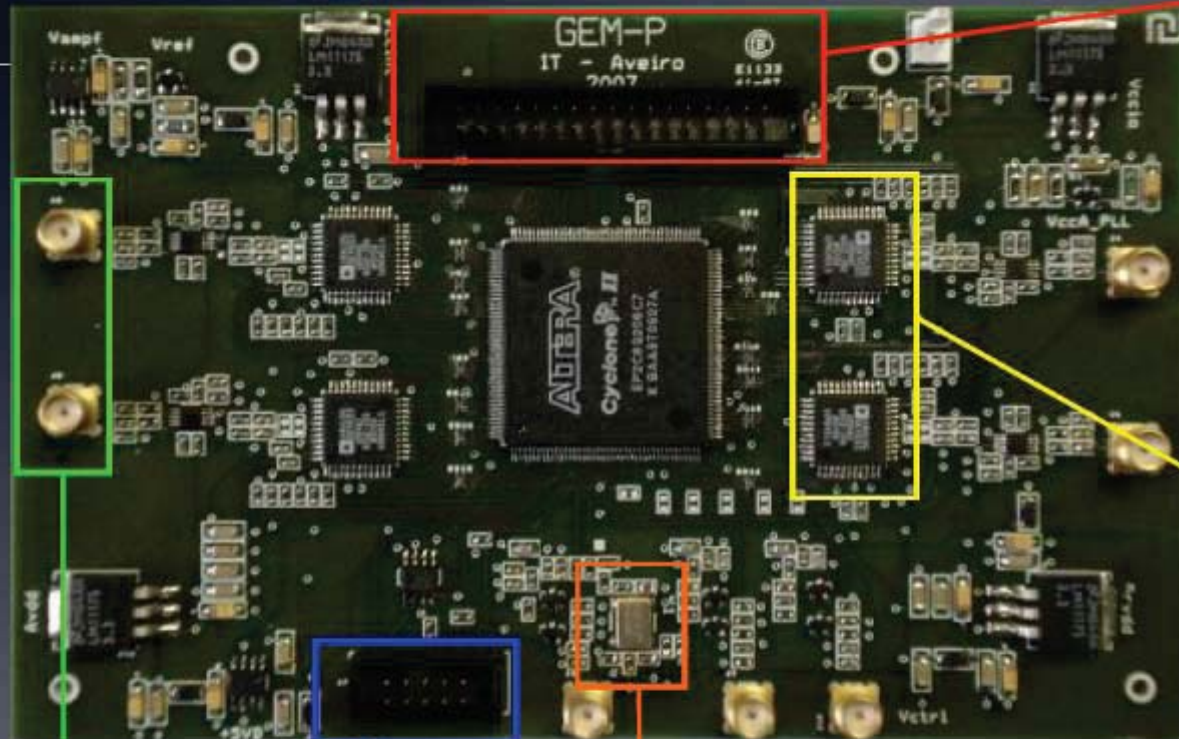
Cryotel GT model (77K nominal;
operation 40K)

GEM-P frontend; InP LNAs)

(Dewar in implementation)



Digital backend (GEM)



ISA Interface output

$$RL = \Re e(E_{rcp} E_{lcp}^*) \rightarrow \text{Stokes } U$$

$$LR = \Re e(E_{rcp, -\frac{\pi}{2}} E_{lcp}^*) \rightarrow \text{Stokes } Q$$

$$RR + LL = \langle E_{rcp} E_{rcp}^* \rangle + \langle E_{lcp} E_{lcp}^* \rangle \rightarrow \text{Stokes } I$$

- ADCs AD9481 from Analog Devices.
- 250 Msp/s
- 8 bits of resolution

Analog inputs

Cristal Oscilator
100 MHz

Active Serial mode
programming interface

- **FPGA EP2C8Q208C7 Cyclone II from ALTERA**
- 8256 LE.
- Number of 9 bits multipliers = 36;
- 208 pins
- Speedgrade 7